# NSN 5961-01-094-8184

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# Inclosure Material:

Metal

# **Overall Length:**

Between 0.250 inches and 0.450 inches

# **Overall Diameter:**

0.875 inches

# **Mounting Facility Quantity:**

2

## Internal Configuration:

Junction contact

# Joint Electronic Device Engineering Council/jedec/case Outline Designation:

## To-3

Electrode Internally-electrically Connected To Case:

Collector

## **Mounting Method:**

Unthreaded hole

# Features Provided:

Hermetically sealed case

# Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

900.0 breakdown voltage, collector-to-emitter, base open and 5.0 breakdown voltage, emitter-to-base, collector open

# **Current Rating Per Characteristic:**

Between 2.00 amperes source cutoff current and 3.00 amperes source cutoff current

## **Power Rating Per Characteristic:**

50.0 watts small-signal input power, common-collector

## Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

## **Special Features:**

Junction pattern arrangement: npn

## **Terminal Type And Quantity:**

1 case and 2 pin

Shelf Life:

N/a

## Unit Of Measure:

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## Demilitarization:

No

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